

**ESD PROTECTION DEVICE**

STAND-OFF VOLTAGE – **5.0** Volts  
POWER DISSIPATION – **40** WATTS

**GENERAL DESCRIPTION**

The L04ESD5V0CP2 is designed to protect sensitive semiconductor components from damage or upset due to Electro Static Discharge (ESD).

**FEATURES**

- Protects one data or I/O line
- Max. peak pulse power : P<sub>pp</sub> = 40W at t<sub>p</sub> = 8/20 us.
- Low clamping voltage
- IEC 61000-4-2, level 4 ( ESD ), > ±15KV ( air ); > ±8KV ( contact )

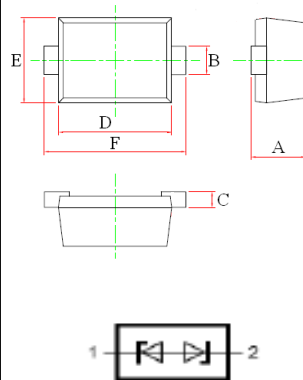
**APPLICATION**

- Computers and peripherals
- Communication system
- Audio & video equipment
- Portable Instrumentation

**MECHANICAL DATA**

- Terminals: Lead Free Plating (Matte Tin Finish)
- Component in accordance to RoHs 2002/95/E

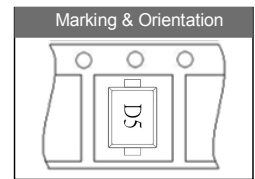
**SOD-923**



SOD-923		
DIM.	MIN.	MAX.
A	0.36	0.41
B	0.18	0.26
C	0.08	0.14
D	0.76	0.84
E	0.56	0.64
F	0.92	1.08

All Dimensions in millimeter

PIN ASSIGNMENT	
1	Cathode
2	Cathode



**MAXIMUM RATINGS (T<sub>j</sub>= 25°C unless otherwise noticed)**

Rating	Symbol	Value	Unit
Peak Pulse Power (t <sub>p</sub> = 8/20us)	P <sub>pk</sub>	40 (Max)	W
Peak Pulse Current (t <sub>p</sub> = 8/20us)	I <sub>pp</sub>	3.5	A
Operating Junction Temperature Range	T <sub>J</sub>	-55 to + 125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to + 150	°C
Soldering Temperature, t max = 10s	T <sub>L</sub>	260	°C

**ELECTRICAL CHARACTERISTICS (T<sub>j</sub>= 25°C unless otherwise noticed)**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse standoff voltage	V <sub>RWM</sub>		---	---	5.0	V
Breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 1 mA	5.5	---	8.5	V
Reverse leakage current	I <sub>RM</sub>	V <sub>DRM</sub> = 5V	---	---	0.1	uA
Clamping Voltage	V <sub>C</sub>	I <sub>pp</sub> = 1A, t <sub>p</sub> = 8/20μs	---	---	9.0	V
Clamping Voltage	V <sub>C</sub>	I <sub>pp</sub> = 3.5A, t <sub>p</sub> = 8/20μs	---	---	12.5	V
Junction capacitance	C <sub>J</sub>	V <sub>R</sub> = 0V, f = 1MHz	---	4.5	---	pF

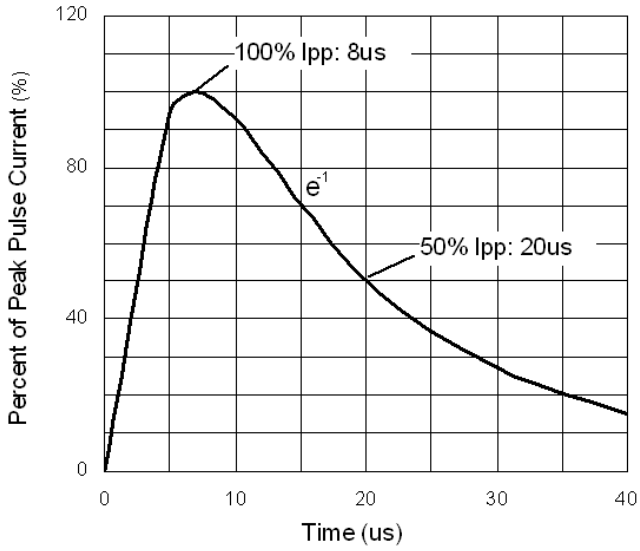


Figure 1. 8/20 us pulse waveform according to IEC 61000-4-5

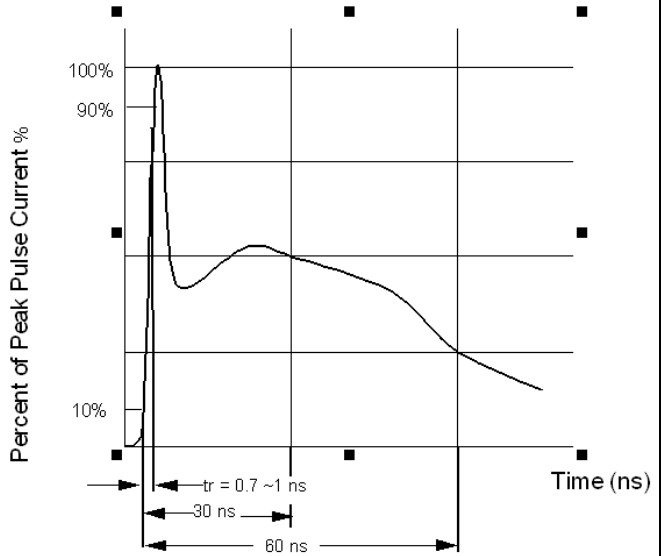


Figure 2. ESD pulse waveform according to IEC 61000-4-2

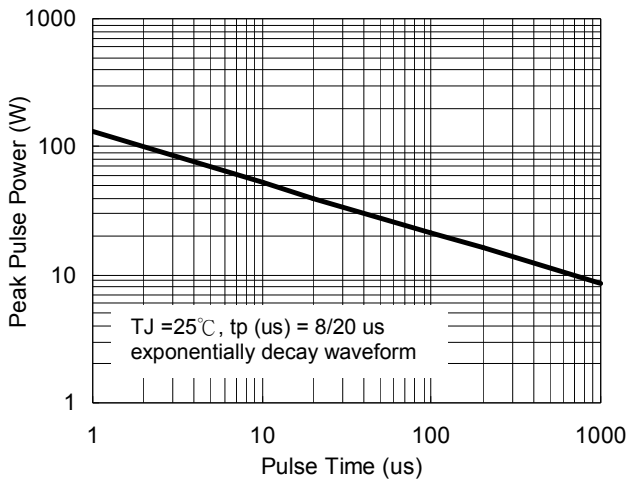


Figure 3. Power Dissipation versus Pulse Time

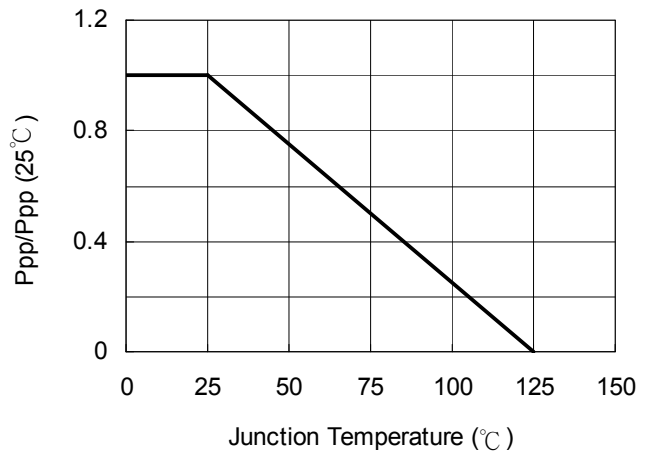


Figure 4. Peak pulse power versus TJ

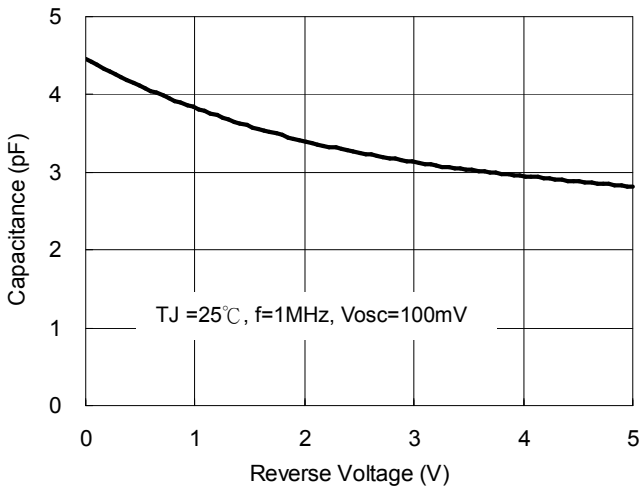


Figure 5. Typical Junction Capacitance

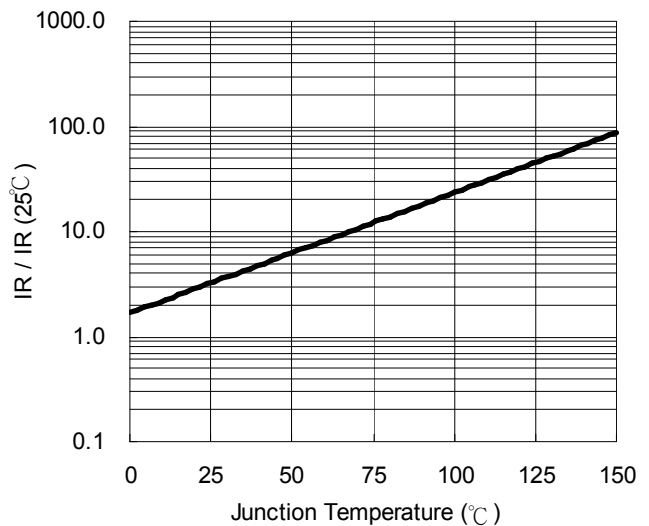


Figure 6. Reverse Leakage Current versus TJ

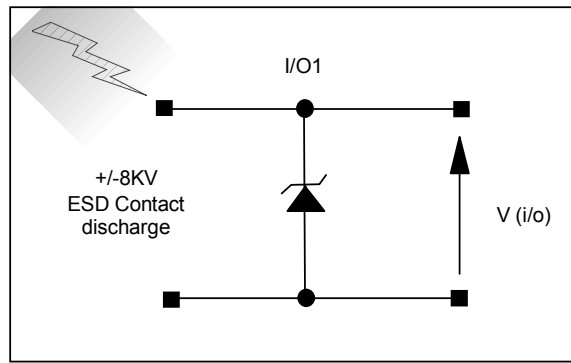


Figure 7. ESD Test Configuration

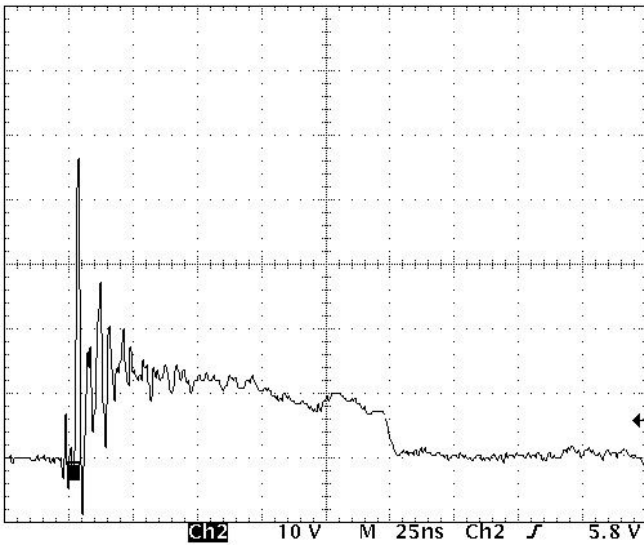


Figure 8. Clamped +8 kV ESD voltage waveform

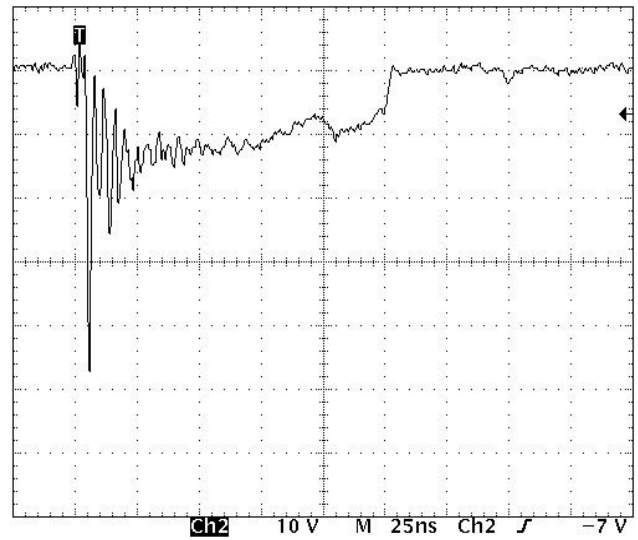


Figure 9. Clamped -8 kV ESD voltage waveform

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